



Vincotech

flow3xBOOST 0	
	600 V / 41 mΩ
Features	
<ul style="list-style-type: none">• High efficiency dual booster• Low Inductance Layout• Ultra fast switching frequency• Integrated DC link capacitor• Integrated temperature sensor	
Target applications	flow 0 12 mm housing
<ul style="list-style-type: none">• Charging Stations• Solar Inverters• UPS	
Types	Schematic
<ul style="list-style-type: none">• 10-FZ063BA040MF-M575L08	



10-FZ063BA040MF-M575L08

datasheet

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Maximum Ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
Boost Switch				
Drain-source voltage	V_{DSS}	$V_{GS} = 0 \text{ V}$ $I_D = 0,25 \text{ mA}$	600	V
Drain current	I_D	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	34	A
Peak drain current	I_{Dpulse}	t_p limited by T_{jmax}	272	A
Avalanche energy, single pulse	E_{AS}	$I_D = 13,4 \text{ A}$ $V_{DD} = 50 \text{ V}$	1954	mJ
Avalanche energy, repetitive	E_{AR}	$I_D = 13,4 \text{ A}$ $V_{DD} = 50 \text{ V}$	2,96	mJ
Avalanche current, repetitive	I_{AR}	t_p limited by T_{jmax} $P_{AV} = E_{AR} \cdot f$	13,4	A
MOSFET dv/dt ruggedness	dv/dt	$V_{DS} = 0...480 \text{ V}$	50	V/ns
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	110	W
Gate-source voltage	V_{GSS}		± 20	V
Reverse diode dv/dt	dv/dt	$V_{DS} = 0...400 \text{ V}$	15	V/ns
Maximum Junction Temperature	T_{jmax}		150	°C
Boost Diode				
Peak repetitive reverse voltage	V_{RRM}		600	V
Continuous (direct) forward current	I_F	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	38	A
Surge (non-repetitive) forward current	I_{FSM}	60 Hz Single Half Sine Wave $t_p = 8,3 \text{ ms}$	300	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	65	W
Maximum junction temperature	T_{jmax}		175	°C
Capacitor (DC)				
Maximum DC voltage	V_{MAX}		630	V
Operation Temperature	T_{op}		-55...+125	°C



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Maximum Ratings

$T_j = 25 \text{ } ^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
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Module Properties

Thermal Properties

Storage temperature	T_{stg}		-40...+125	$^\circ\text{C}$
Operation temperature under switching condition	T_{jop}		-40...($T_{\text{jmax}} - 25$)	$^\circ\text{C}$

Isolation Properties

Isolation voltage	V_{isol}	DC Test Voltage*	$t_p = 2 \text{ s}$	6000	V
		AC Voltage	$t_p = 1 \text{ min}$	2500	V
Creepage distance				min. 12,7	mm
Clearance				min. 12,7	mm
Comparative Tracking Index	CTI			> 200	

*100 % tested in production



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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_c [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max		

Boost Switch

Static

Drain-source on-state resistance	$r_{DS(on)}$		10		44,4	25 125		41 84	51,8	$\text{m}\Omega$
Gate-source threshold voltage	$V_{GS(\text{th})}$	$V_{GS} = V_{DS}$			0,00296	25	2,4	3	3,6	V
Gate to Source Leakage Current	I_{GS}		20	0		25			100	nA
Zero Gate Voltage Drain Current	I_{DS}		0	600		25			5	μA
Internal gate resistance	r_g	$f = 1\text{MHz}$	0	100		25		0,7		Ω
Gate charge	Q_g	$f = 1\text{MHz}$	0/10	480	44,4	25		290		nC
Gate to source charge	Q_{GS}							36		
Gate to drain charge	Q_{GD}							150		
Short-circuit input capacitance	C_{iss}	$f = 1\text{MHz}$	0	100	25			6530		pF
Short-circuit output capacitance	C_{oss}							360		

Reverse Diode Static

Diode forward voltage	V_{SD}		0		44,4	25		0,9		V
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Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{\text{paste}} = 3,4 \text{ W/mK}$ (PSX)						0,64		K/W
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Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{gon} = 8 \Omega$ $R_{goff} = 8 \Omega$	10/0	400	15	25 125		35 33		ns
Rise time	t_r					25 125		9 10		
Turn-off delay time	$t_{d(off)}$					25 125		275 300		
Fall time	t_f					25 125		4 5		
Turn-on energy (per pulse)	E_{on}					25 125		0,181 0,335		
Turn-off energy (per pulse)	E_{off}					25 125		0,071 0,083		



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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_c [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max		

Boost Diode

Static

Forward voltage	V_F				30	25 125 150		2,32 1,78 1,67	2,78		V
Reverse leakage current	I_R			600		25 150			100 500		µA

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						1,46		K/W
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Dynamic

Peak recovery current	I_{RRM}	$di/dt = 1844 \text{ A/µs}$ $di/dt = 1583 \text{ A/µs}$	10/0	400	15	25		18 30		A
Reverse recovery time	t_{rr}					25 125		14 32		ns
Recovered charge	Q_r					25 125		0,150 0,559		µC
Reverse recovered energy	E_{rec}					25 125		0,015 0,075		mWs
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					25 125		5321 1723		A/µs

Capacitor (DC)

Capacitance	C							47		nF
Tolerance							-10		+10	%
Climatic category							55/125/56			

Thermistor

Rated resistance	R					25		22		kΩ
Deviation of R_{100}	$\Delta_{R/R}$	$R_{100} = 1486 \Omega$				100	-12		+14	%
Power dissipation	P					25		200		mW
Power dissipation constant						25		2		mW/K
B-value	$B_{(25/50)}$	Tol. ±3%				25		3950		K
B-value	$B_{(25/100)}$	Tol. ±3%				25		3998		K
Vincotech NTC Reference									B	



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Boost Switch Characteristics

figure 1. MOSFET

Typical output characteristics
 $I_D = f(V_{DS})$

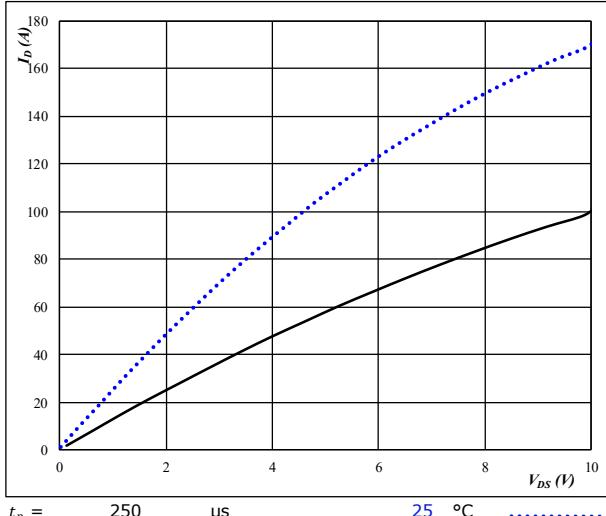


figure 2. MOSFET

Typical output characteristics
 $I_D = f(V_{DS})$

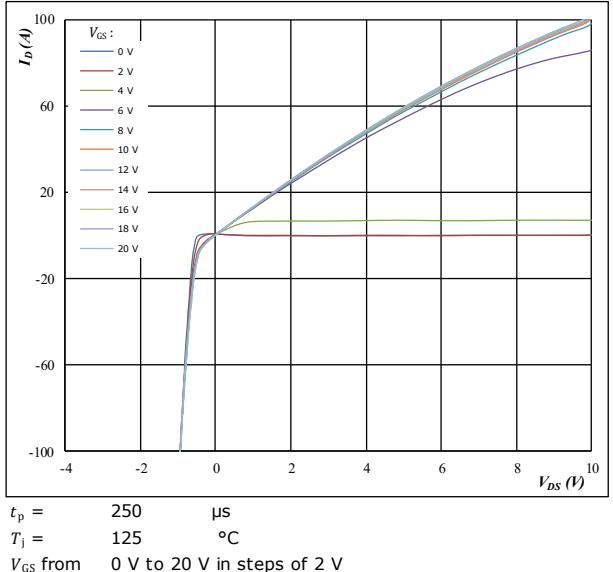


figure 3. MOSFET

Typical transfer characteristics
 $I_D = f(V_{GS})$

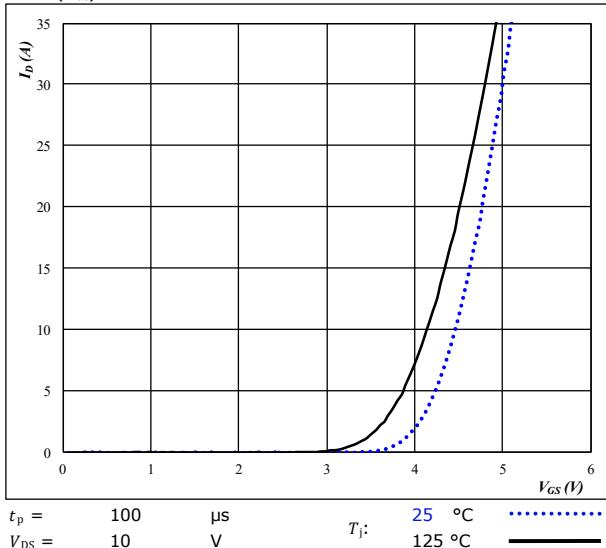
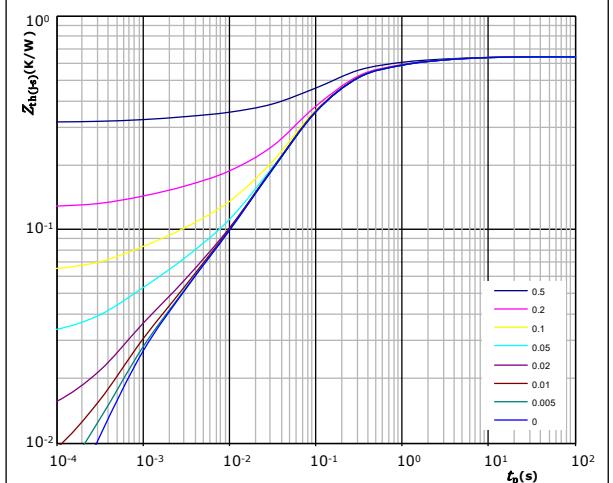


figure 4. MOSFET

Transient thermal impedance as a function of pulse width

$Z_{th(t_p)} = f(t_p)$



MOSFET thermal model values

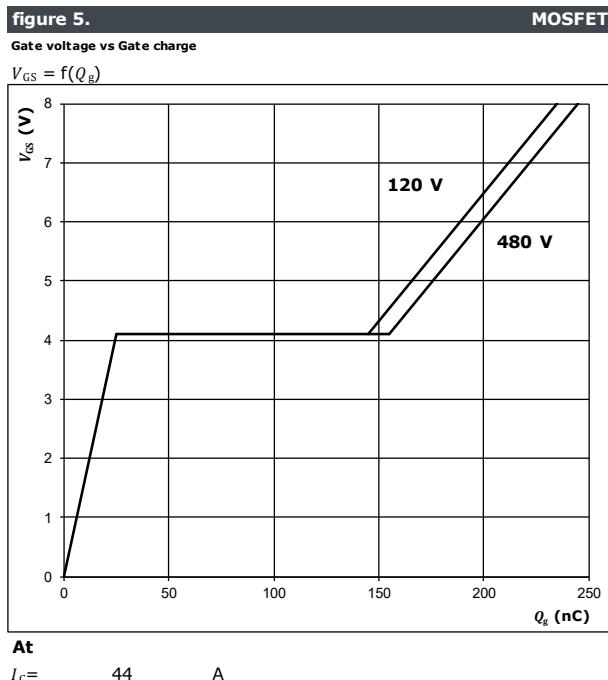
R (K/W)	τ (s)
3,27E-02	5,10E+00
7,82E-02	9,69E-01
2,46E-01	1,76E-01
2,22E-01	6,63E-02
3,32E-02	6,97E-03
2,51E-02	9,25E-04



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Boost Switch Characteristics

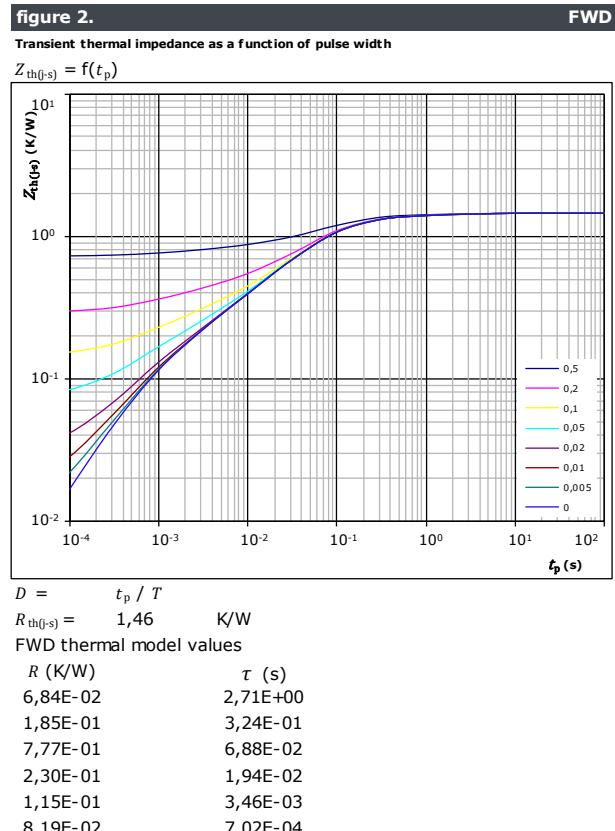
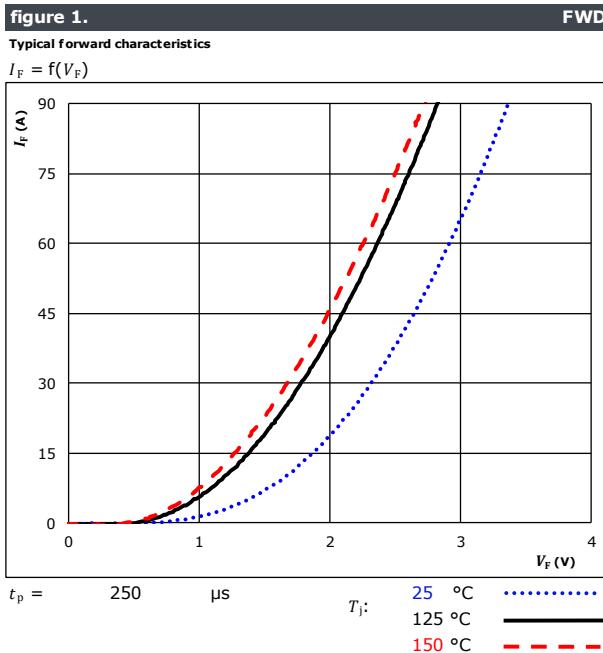




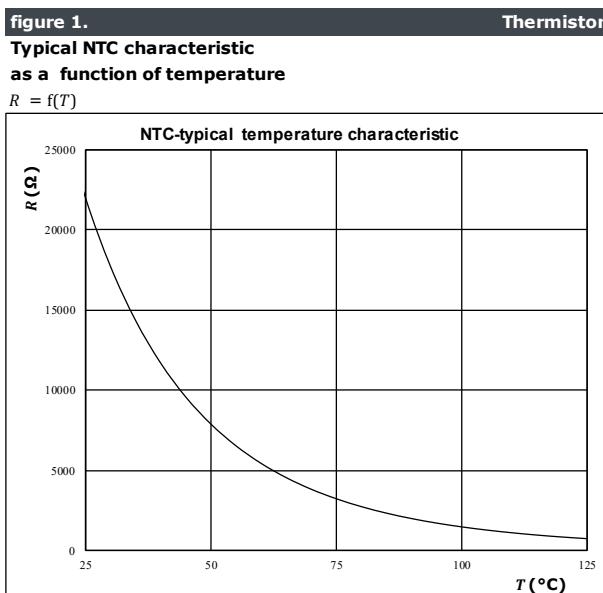
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Boost Diode Characteristics



Thermistor Characteristics



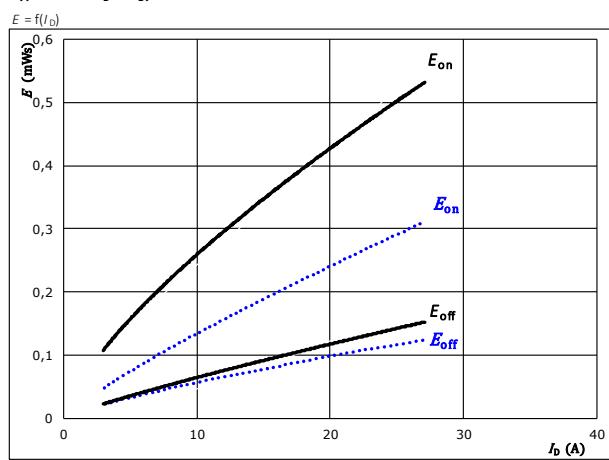


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Boost Switching Characteristics

figure 1. MOSFET

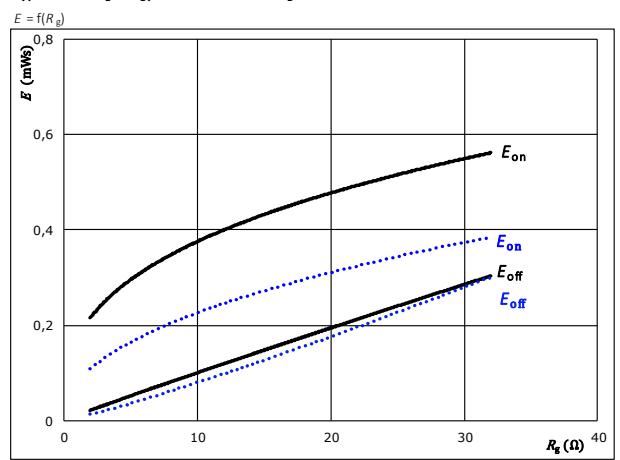
Typical switching energy losses as a function of drain current



With an inductive load at
 $V_{DS} = 400$ V $T_j: 25$ °C
 $V_{GS} = 10/0$ V $T_j: 125$ °C
 $R_{gon} = 8$ Ω
 $R_{goff} = 8$ Ω

figure 2. MOSFET

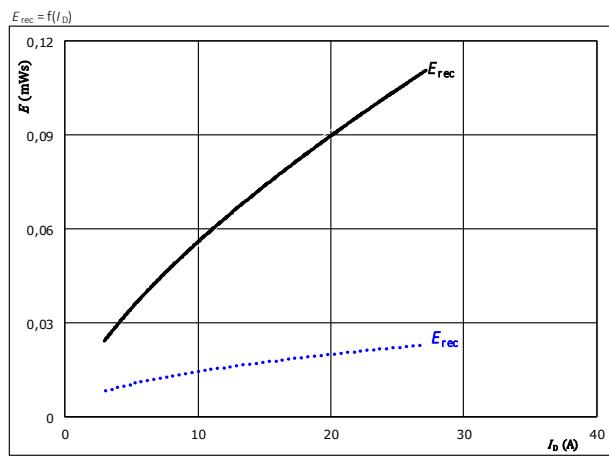
Typical switching energy losses as a function of gate resistor



With an inductive load at
 $V_{DS} = 400$ V $T_j: 25$ °C
 $V_{GS} = 10/0$ V $T_j: 125$ °C
 $I_D = 15$ A

figure 3. FWD

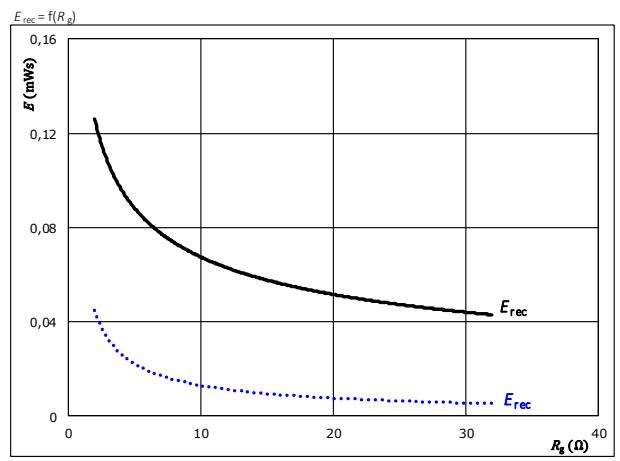
Typical reverse recovered energy loss as a function of drain current



With an inductive load at
 $V_{DS} = 400$ V $T_j: 25$ °C
 $V_{GS} = 10/0$ V $T_j: 125$ °C
 $R_{gon} = 8$ Ω

figure 4. FWD

Typical reverse recovered energy loss as a function of gate resistor

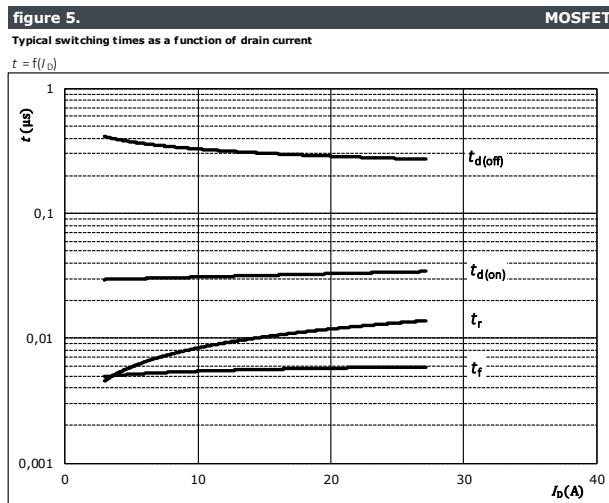


With an inductive load at
 $V_{DS} = 400$ V $T_j: 25$ °C
 $V_{GS} = 10/0$ V $T_j: 125$ °C
 $I_D = 15$ A

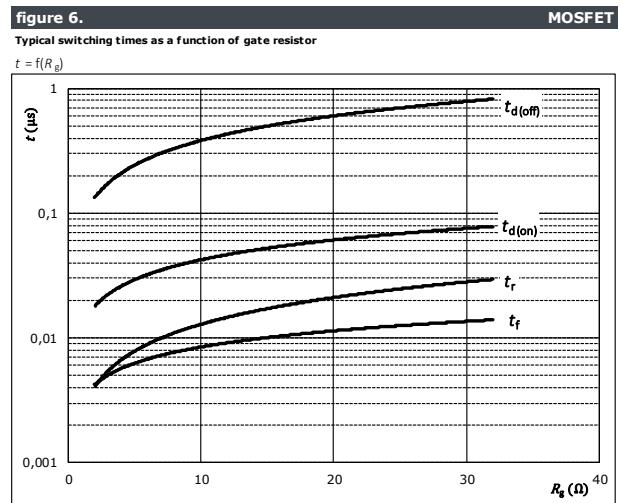


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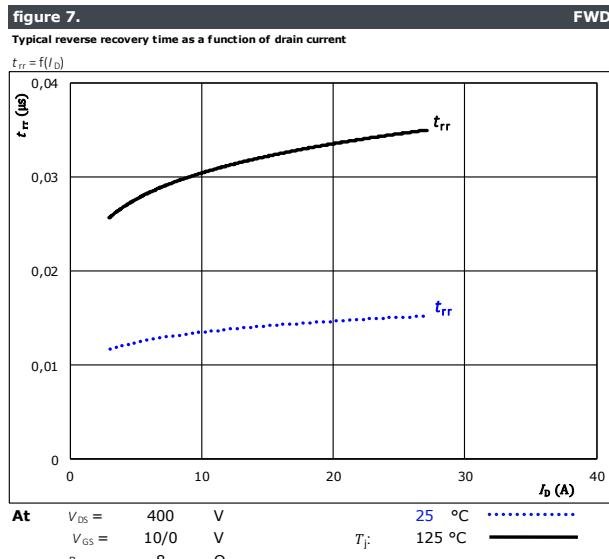
Boost Switching Characteristics



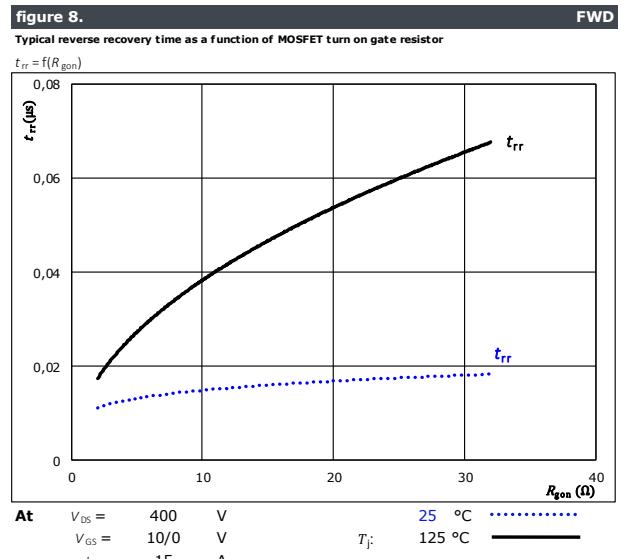
With an inductive load at
 $T_J = 125^\circ\text{C}$
 $V_{DS} = 400 \text{ V}$
 $V_{GS} = 10/0 \text{ V}$
 $R_{gon} = 8 \Omega$
 $R_{goff} = 8 \Omega$



With an inductive load at
 $T_J = 125^\circ\text{C}$
 $V_{DS} = 400 \text{ V}$
 $V_{GS} = 10/0 \text{ V}$
 $I_D = 15 \text{ A}$



At $V_{DS} = 400 \text{ V}$ $V_{GS} = 10/0 \text{ V}$ $R_{gon} = 8 \Omega$ $T_J = 25^\circ\text{C}$ $I_D = 15 \text{ A}$ $t_{rr} = 0,016 \mu\text{s}$

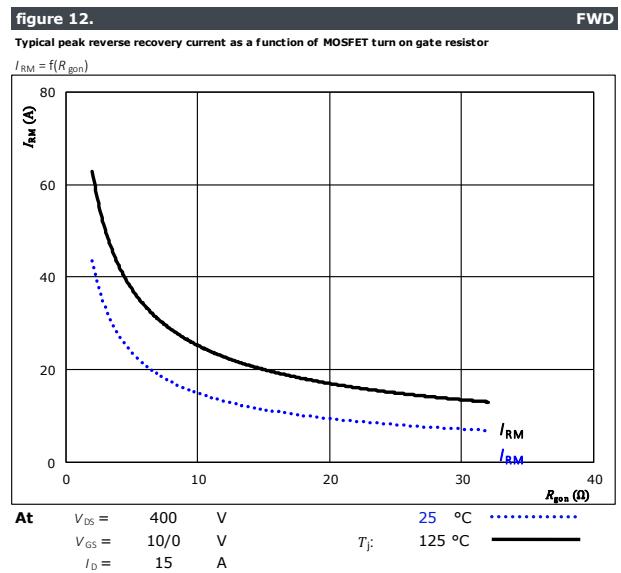
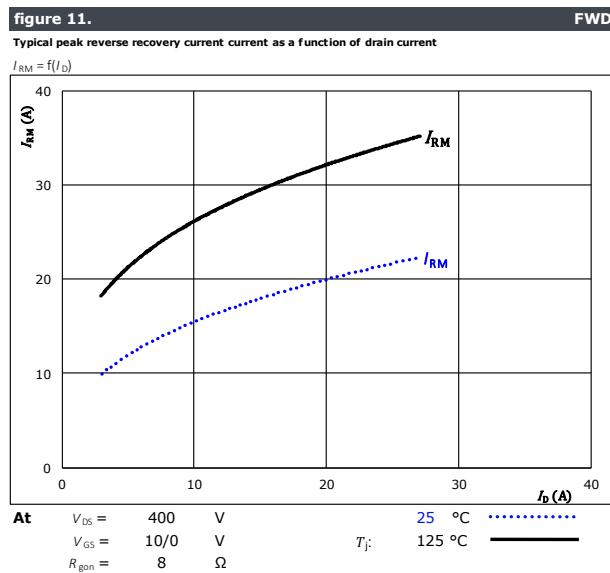
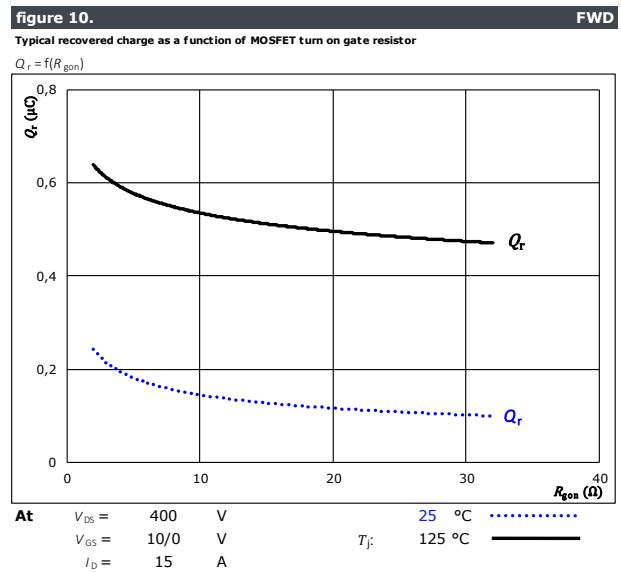
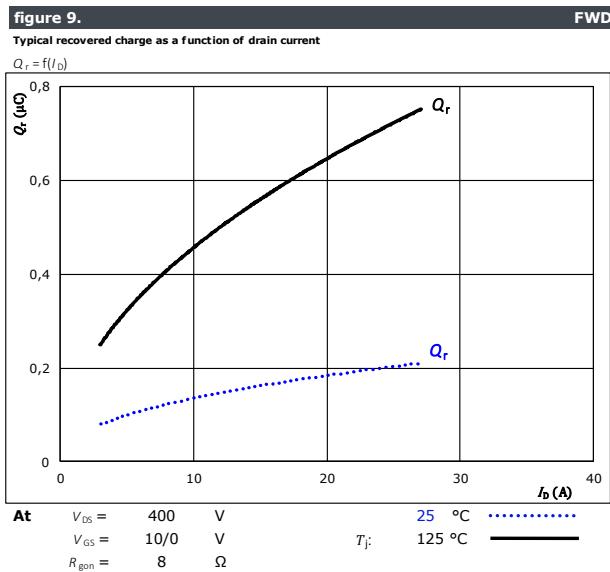


At $V_{DS} = 400 \text{ V}$ $V_{GS} = 10/0 \text{ V}$ $I_D = 15 \text{ A}$ $T_J = 25^\circ\text{C}$ $t_{rr} = 0,016 \mu\text{s}$



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Boost Switching Characteristics

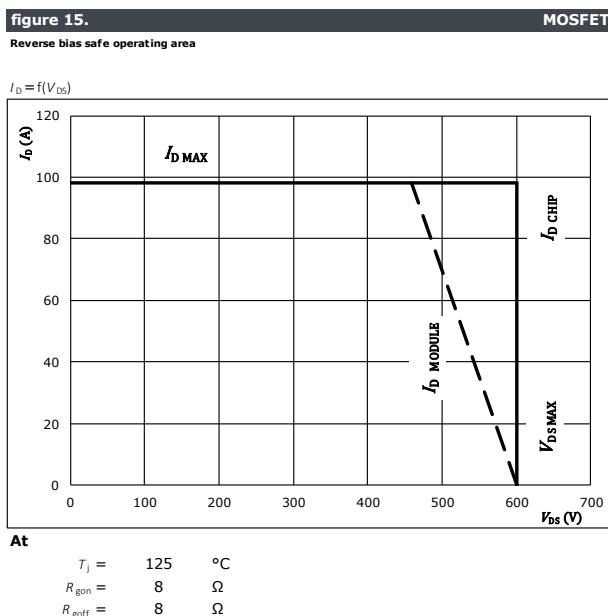
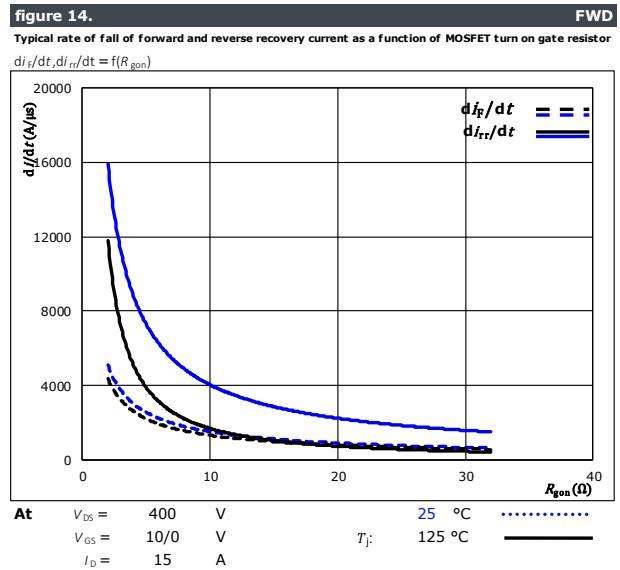
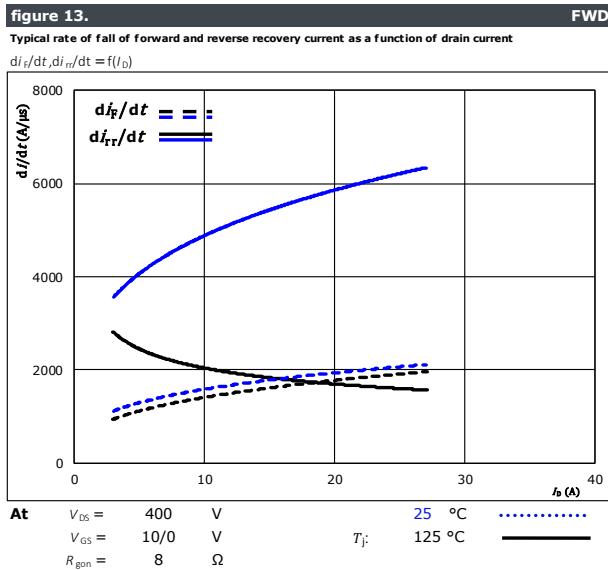




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Boost Switching Characteristics





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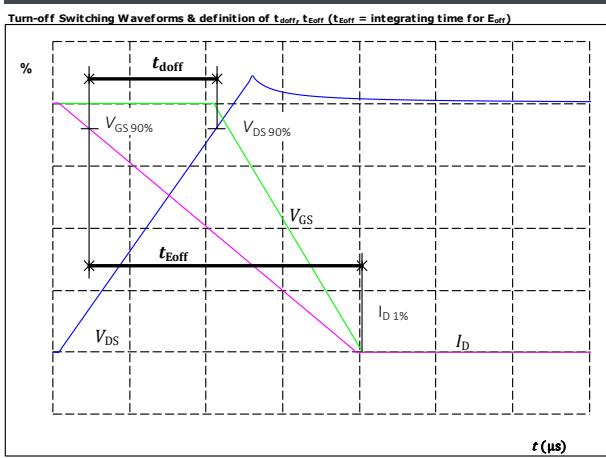
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Boost Switching Definitions

General conditions

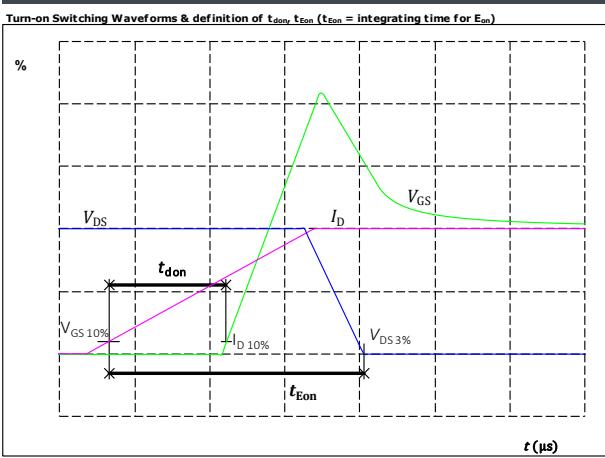
T_J	=	125 °C
R_{gon}	=	8 Ω
R_{goff}	=	8 Ω

figure 1.



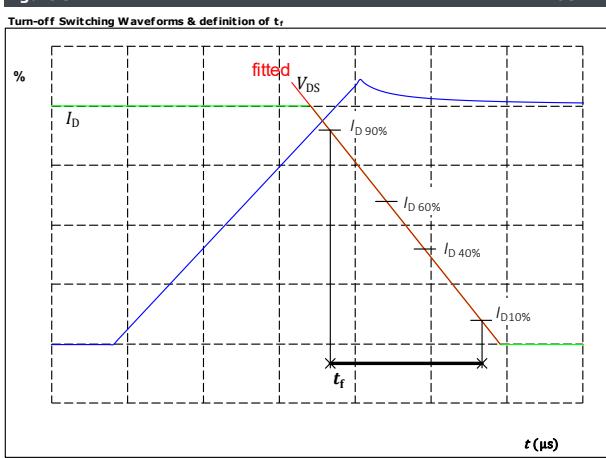
$V_{GS\ (0\%)} = 0 \text{ V}$
 $V_{GS\ (100\%)} = 10 \text{ V}$
 $V_{DS\ (100\%)} = 400 \text{ V}$
 $I_D\ (100\%) = 15 \text{ A}$
 $t_{doff} = 0,300 \text{ } \mu\text{s}$

figure 2.



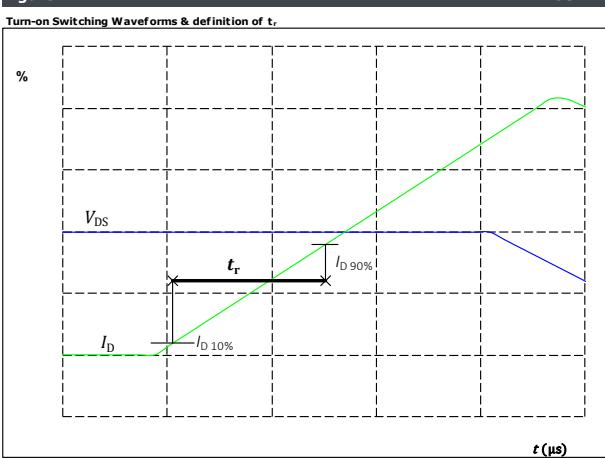
$V_{GS\ (0\%)} = 0 \text{ V}$
 $V_{GS\ (100\%)} = 10 \text{ V}$
 $V_{DS\ (100\%)} = 400 \text{ V}$
 $I_D\ (100\%) = 15 \text{ A}$
 $t_{don} = 0,033 \text{ } \mu\text{s}$

figure 3.



$V_{DS\ (100\%)} = 400 \text{ V}$
 $I_D\ (100\%) = 15 \text{ A}$
 $t_f = 0,005 \text{ } \mu\text{s}$

figure 4.



$V_{DS\ (100\%)} = 400 \text{ V}$
 $I_D\ (100\%) = 15 \text{ A}$
 $t_r = 0,010 \text{ } \mu\text{s}$



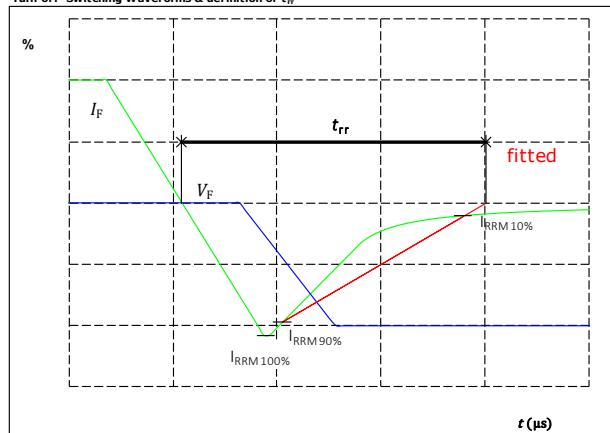
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Boost Switching Characteristics

figure 7.

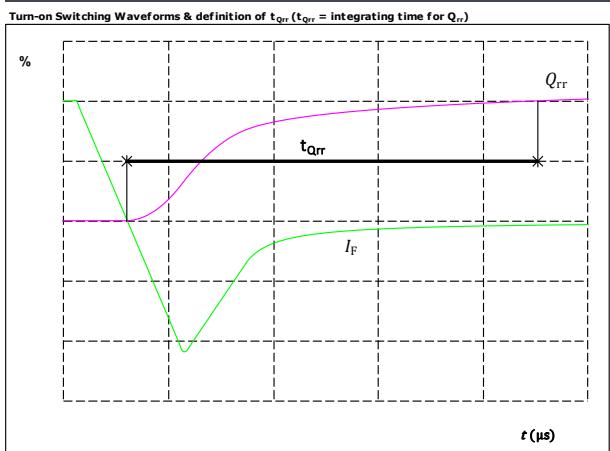
Turn-off Switching Waveforms & definition of t_{rr}



$I_F(100\%) = 400 \text{ A}$
 $I_F(100\%) = 15 \text{ V}$
 $I_{RRM}(100\%) = 30 \text{ A}$
 $t_{rr} = 0,032 \mu\text{s}$

figure 8.

Turn-on Switching Waveforms & definition of t_{Qrr} (t_{Qrr} = integrating time for Q_{rr})



$I_F(100\%) = 15 \text{ A}$
 $Q_{rr}(100\%) = 0,56 \mu\text{C}$

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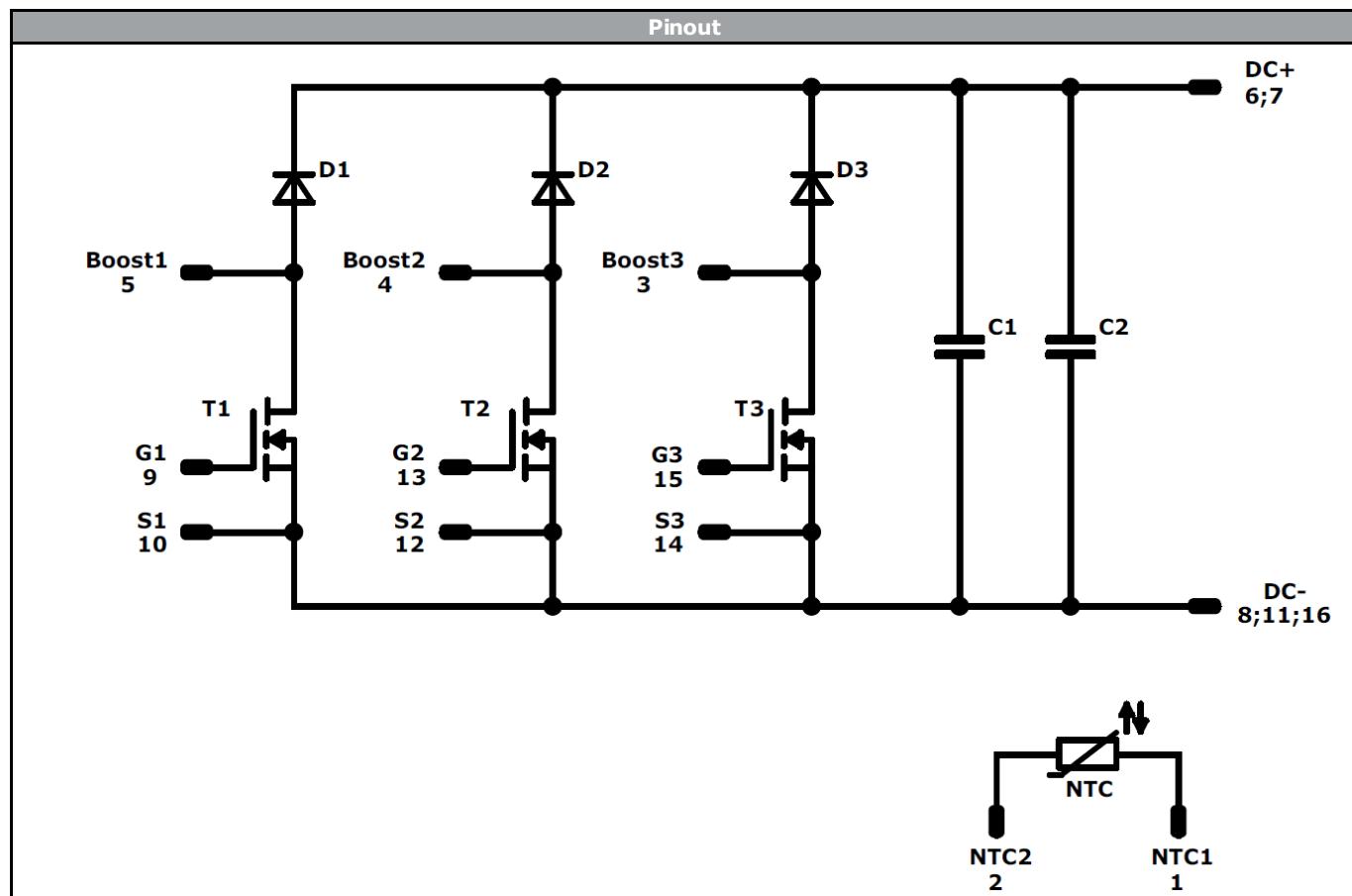
Ordering Code & Marking																																																																											
Version				Ordering Code																																																																							
without thermal paste 12 mm housing with solder pins				10-FZ063BA040MF-M575L08																																																																							
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		Text	Name		Date code	UL & VIN	Lot																																																																				
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Outline																																																																											
Pin table																																																																											
<table border="1"><thead><tr><th>Pin</th><th>X</th><th>Y</th><th>Function</th></tr></thead><tbody><tr><td>1</td><td>33,3</td><td>0</td><td>NTC1</td></tr><tr><td>2</td><td>30,7</td><td>0</td><td>NTC2</td></tr><tr><td>3</td><td>23,85</td><td>0</td><td>Boost3</td></tr><tr><td>4</td><td>15,95</td><td>0</td><td>Boost2</td></tr><tr><td>5</td><td>9,6</td><td>0</td><td>Boost1</td></tr><tr><td>6</td><td>2,6</td><td>0</td><td>DC+</td></tr><tr><td>7</td><td>0</td><td>0</td><td>DC+</td></tr><tr><td>8</td><td>0</td><td>22,3</td><td>DC-</td></tr><tr><td>9</td><td>2,6</td><td>22,3</td><td>G1</td></tr><tr><td>10</td><td>5,5</td><td>22,3</td><td>S1</td></tr><tr><td>11</td><td>13,1</td><td>22,3</td><td>DC-</td></tr><tr><td>12</td><td>15,9</td><td>22,3</td><td>S2</td></tr><tr><td>13</td><td>19,4</td><td>22,3</td><td>G2</td></tr><tr><td>14</td><td>27,7</td><td>22,3</td><td>S3</td></tr><tr><td>15</td><td>30,7</td><td>22,3</td><td>G3</td></tr><tr><td>16</td><td>33,3</td><td>22,3</td><td>DC-</td></tr></tbody></table>								Pin	X	Y	Function	1	33,3	0	NTC1	2	30,7	0	NTC2	3	23,85	0	Boost3	4	15,95	0	Boost2	5	9,6	0	Boost1	6	2,6	0	DC+	7	0	0	DC+	8	0	22,3	DC-	9	2,6	22,3	G1	10	5,5	22,3	S1	11	13,1	22,3	DC-	12	15,9	22,3	S2	13	19,4	22,3	G2	14	27,7	22,3	S3	15	30,7	22,3	G3	16	33,3	22,3	DC-
Pin	X	Y	Function																																																																								
1	33,3	0	NTC1																																																																								
2	30,7	0	NTC2																																																																								
3	23,85	0	Boost3																																																																								
4	15,95	0	Boost2																																																																								
5	9,6	0	Boost1																																																																								
6	2,6	0	DC+																																																																								
7	0	0	DC+																																																																								
8	0	22,3	DC-																																																																								
9	2,6	22,3	G1																																																																								
10	5,5	22,3	S1																																																																								
11	13,1	22,3	DC-																																																																								
12	15,9	22,3	S2																																																																								
13	19,4	22,3	G2																																																																								
14	27,7	22,3	S3																																																																								
15	30,7	22,3	G3																																																																								
16	33,3	22,3	DC-																																																																								
Tolerance of pinpositions: ±0.5mm at the end of pins Dimension of coordinate axis is only offset without tolerance																																																																											



10-FZ063BA040MF-M575L08

datasheet

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Identification					
ID	Component	Voltage	Current	Function	Comment
T1, T2, T3	MOSFET	600 V	41 mΩ	Boost Switch	
D1, D2, D3	FWD	600 V	30 A	Boost Diode	
C1, C2	Capacitor	630 V		Capacitor (DC)	
NTC	NTC			Thermistor	



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Packaging instruction			
Standard packaging quantity (SPQ) 135	>SPQ	Standard	<SPQ Sample

Handling instruction			
Handling instructions for flow 0 packages see vincotech.com website.			

Package data			
Package data for flow 0 packages see vincotech.com website.			

UL recognition and file number			
This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website.			

Document No.:	Date:	Modification:	Pages
10-FZ063BA040MF-M575L08-D6-14	22 Mar. 2019	Correction of I _c /I _f values	2

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As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in labelling can be reasonably expected to result in significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.